ON Semiconductor®



ASM3P2182A

LCD Panel EMI Reduction IC

Features

- FCC approved method of EMI attenuation.
- Provides up to 15dB EMI reduction.
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Input frequency range: 25MHz to 210MHz.
- Internal loop filter minimizes external components and board space.
- Center spread.
- 4 spread frequency deviation selections: ± 0.13% to ± 1.24%.
- Low inherent Cycle-to-cycle jitter.
- 3.3V Operating Voltage.
- TTL or CMOS compatible inputs and outputs.
- Low power CMOS design.
- Supports notebook VGA and other LCD timing controller applications.
- Available in 8-pin SOIC Package.

Product Description

The ASM3P2182A is a versatile spread spectrum frequency modulator designed specifically for a wide range of input clock frequencies from 25MHz to 210MHz. (Refer to *Input Frequency and Modulation Rate Table*). The ASM3P2182A can generate an EMI reduced clock from an OSC or a system generated clock. The ASM3P2182A offers a Center Spread clock and with a percentage deviation from $\pm 0.13\%$ or $\pm 1.24\%$.

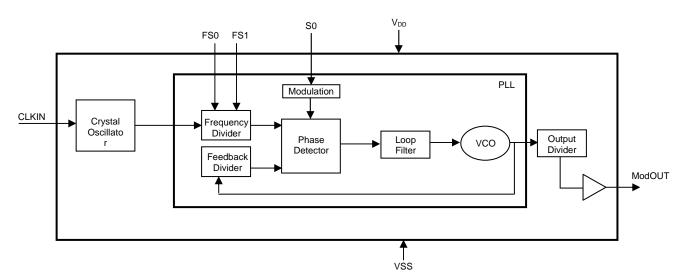
The ASM3P2182A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of down stream clock and data dependent signals. The ASM3P2182A allows significant system cost savings by reducing the number of circuit board layers ferrite beads, shielding and other passive components that are traditionally required to pass EMI regulations.

The ASM3P2182A uses the most efficient and optimized modulation profile approved by the FCC and is implemented in a proprietary all digital method.

The ASM3P2182A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation.'

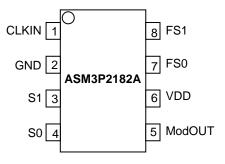
Applications

The ASM3P2182A is targeted towards EMI management for memory and LVDS interfaces in mobile graphic chipsets and high-speed digital applications such as PC peripheral devices, consumer electronics, and embedded controller systems.



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Pin Configuration



Pin Description

Pin#	Pin Name	Туре	Description
1	CLKIN	I	Connect to externally generated clock signal.
2	GND	Р	Ground to entire chip.
3	S1	I	Spread range select. Digital logic input used to select frequency deviation (Refer to <i>Spread Deviation Table</i>). This pin has an internal pull-up resistor.
4	S0	Ι	Spread range select. Digital logic input used to select frequency deviation (Refer to <i>Spread Deviation Table</i>). This pin has an internal pull-up resistor.
5	ModOUT	0	Spread spectrum low EMI output.
6	VDD	Р	Power supply for the entire chip (3.3V).
7	FS0	I	Frequency range select. Digital logic input used to select frequency range (Refer to <i>Input Frequency and Modulation Rate Table</i>). This pin has an internal pull-up resistor.
8	FS1	I	Frequency range select. Digital logic input used to select frequency range (Refer to <i>Input Frequency and Modulation Rate Table</i>). This pin has an internal pull-up resistor.

Input Frequency and Modulation Rate table

FS1 (pin 8)	FS0 (pin 7)	Frequency Range
0	0	25MHz to 50MHz
0	1	50MHz to 103MHz
1	0	75MHz to 150MHz
1	1	160MHz to 210MHz

Spread Deviation Selection table

		Spreading Range (± %)								
S1	S0	25 MHz	40 MHz	65 MHz	81 ¹ MHz	81 ² MHz	108 MHz	120 MHz	162 MHz	200 MHz
0	0	0.28	0.19	0.15	0.12	0.18	0.15	0.1	0.1	0.06
0	1	0.8	0.3	0.3	0.2	0.5	0.3	0.19	0.3	0.1
1	0	1.2	0.54	0.45	0.4	0.8	0.6	0.36	1.0	0.6
1	1	2.1	1.0	1.1	0.9	1.4	1.1	0.75	1.9	1.2

Notes: 1. Frequency Range- 50MHz to 103MHz 2. Frequency Range- 75MHz to 150MHz

Symbol	Parameter	Rating	Unit
VDD	Supply Voltage pin with respect to Ground	-0.5 to +4.6	V
V _{IN}	Input Voltage pin with respect to Ground	VSS-0.5 to VDD+0.5	V
V _{OUT}	Output Voltage pin with respect to Ground	VSS-0.5 to VDD+0.5	V
T _{STG}	Storage temperature	-55 to +125	C
Ts	Max. Soldering Temperature (10 sec)	260	C
TJ	Junction Temperature	150	C
T _{DV}	Static Discharge Voltage (As per JEDEC STD22-A114-B)	2	KV

Recommended Operating Conditions

Parameter	Description	Min	Тур	Мах	Unit
VDD	Operating Voltage	2.7	3.3	3.7	V
T _A	Operating Temperature (Ambient Temperature)	-40		+85	C
CL	Load Capacitance			15	рF
CIN	Input Capacitance		5		рF

Symbol	Parameter	Min	Тур	Max	Unit
VIL	Input low voltage	GND – 0.3		0.8	V
V _{IH}	Input high voltage	2.0		V _{DD} + 0.3	V
IIL	Input low current			-35	μA
Iн	Input high current			35	μA
V _{OL}	Output low voltage ($V_{DD} = 3.3V$, $I_{OL} = 20mA$)			0.4	V
V _{OH}	Output high voltage ($V_{DD} = 3.3V$, $I_{OH} = 20mA$)	2.5			V
Icc	Dynamic supply current Normal mode (3.3V and 10pF loading)	8.46	12	17.78	mA
I _{DD}	Static supply current Standby mode ¹		0.6		mA
V_{DD}	Operating voltage	2.7	3.3	3.7	V
t _{ON}	Power up time (first locked clock cycle after power up)		0.18		mS
ZOUT	Clock out impedance		50		Ω

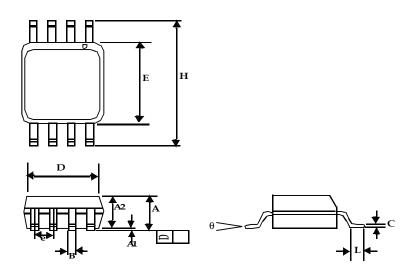
DC Electrical Characteristics

AC Electrical Characteristics

Symbol	Parameter	Min	Тур	Max	Unit
CLKIN	Input frequency	25		210	MHz
ModOUT	Output frequency 25 2		210	MHz	
t _{LH} ¹	Output rise time (measured at 0.8V to 2.0V) 1.2 1.32		1.32	1.4	nS
t _{HL} 1	Output fall time (measured at 2.0V to 0.8V)	0.8	0.9	1.0	nS
t _{JC}	Jitter (cycle to cycle)			±360	pS
T _D	Output duty cycle		50	55	%
Note: 1. t _{LH} and t _{HL} are measured	into a capacitive load of 15pF.		•		

Package Information

8-lead (150-mil) SOIC Package



	Dimensions					
Symbol	Inc	hes	Millimeters			
	Min	Мах	Min	Мах		
A1	0.004	0.010	0.10	0.25		
А	0.053	0.069	1.35	1.75		
A2	0.049	0.059	1.25	1.50		
В	0.012	0.020	0.31	0.51		
С	0.007	0.010	0.18	0.25		
D	0.193	BSC	4.90 BSC			
E	0.154	BSC	3.91 BSC			
е	0.050 BSC		1.27 BSC			
Н	0.236 BSC		6.00 BSC			
L	0.016	0.050	0.41	1.27		
θ	0°	8°	0°	8°		

ASM3P2182A

Ordering Information

Part Number	Marking	Package	Temperature
ASM3P2182AF-08ST	ACV	8-Pin SOIC, TUBE, Pb Free	0℃ to +70℃
ASM3P2182AF-08SR	ACV	8-Pin SOIC, TAPE & REEL, Pb Free	0℃ to +70℃

A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-free.

Licensed under US patent #5,488,627, #6,646,463 and #5,631,920.

Note: This product utilizes US Patent #6,646,463 Impedance Emulator Patent issued to PulseCore Semiconductor, dated 11-11-2003.

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